

### KSD5707

# **High Voltage Color Display Horizontal Deflection Output**

• High Collector - Base Voltage :  $V_{CBO}$  = 1500V • High Speed Switching  $t_F$  = 0.4 $\mu$ s (Max.)



### **NPN Triple Diffused Planar Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	1500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	800	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>C</sub>	Collector Current (DC)	6	А
I <sub>CP</sub>	Collector Current (Pulse)	16	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	60	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 800V, I_{E} = 0$			10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0			1	mA
h <sub>FE1</sub>	DC Current Gain	V <sub>CE</sub> = 5V, I <sub>C</sub> = 1A	10		30	
$h_{FE2}$		$V_{CE} = 5V$ , $I_{C} = 3A$	5		15	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4A, I <sub>B</sub> = 0.8A		2	5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 4A, I <sub>B</sub> = 0.8A			1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1A		3		MHz
t <sub>F</sub>	Fall Time	V <sub>CC</sub> =200V, I <sub>C</sub> =4A,			0.4	μs
		I <sub>B1</sub> = 0.8A, I <sub>B2</sub> = -1.6A				
		$R_L=50\Omega$				

### **Thermal Characteristics**

Symbol	Characteristics		Rating	Unit
$R_{\theta ic}$	Thermal Resistance	Junction to Case	2.08	°C/W

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# **Typical Characteristics**

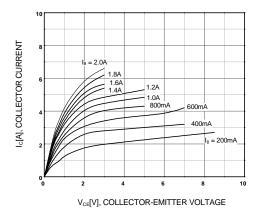


Figure 1. Static Characteristic

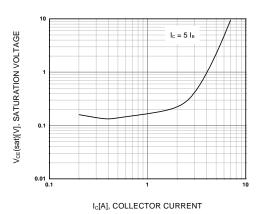


Figure 3. Collector-Emitter Saturation Voltage

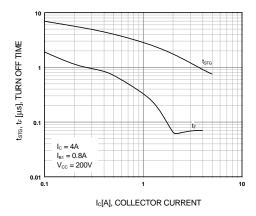


Figure 5. Switching Time

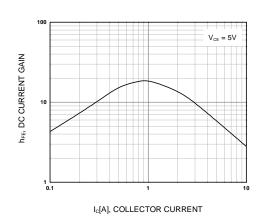


Figure 2. DC current Gain

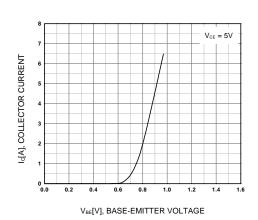


Figure 4. Base-Emitter On Voltage

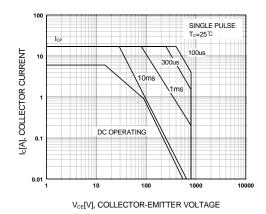


Figure 6. Safe Operating Area

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# Typical Characteristics (Continued)

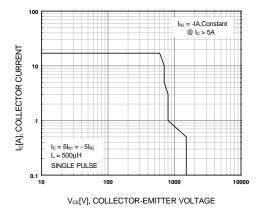


Figure 7. Reverse Bias Safe Operating Area

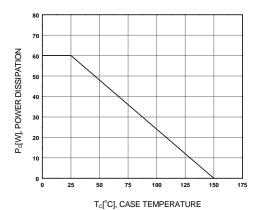
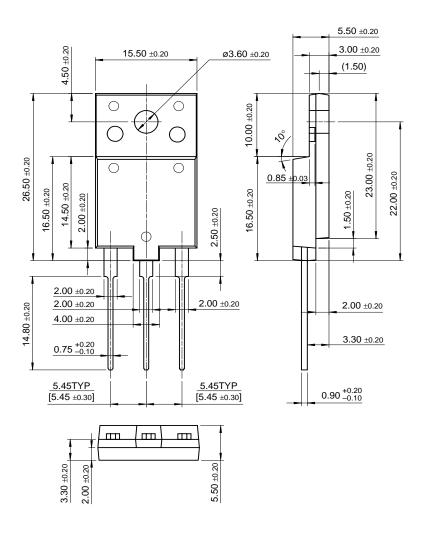


Figure 8. Power Derating

# **Package Demensions**

# TO-3PF



Dimensions in Millimeters

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